Atmel

Atmel AT24CS01 and AT24CS02

I²C-Compatible (2-wire) Serial EEPROM with a Unique, Factory Programmed 128-bit Serial Number 1-Kbit (128 x 8), 2-Kbit (256 x 8)

PRELIMINARY DATASHEET

Standard Features

- Low-voltage operation
 V_{CC} = 1.7V to 5.5V
- Internally organized as 128 x 8 (1-Kbit) or 256 x 8 (2-Kbit)
- I²C-compatible (2-wire) serial interface
- Schmitt Trigger, filtered inputs for noise suppression
- Bidirectional data transfer protocol
- 400kHz (1.7V) and 1MHz (2.5V, 5.0V) compatibility
- Write Protect pin for hardware data protection
 - 8-byte page write mode
 - Partial page writes allowed
- Self-timed write cycle (5ms max)
- High-reliability
 - Endurance: 1,000,000 write cycles
 - Data retention: 100 years
- Green package options (Pb/Halide-free/RoHS-compliant)
 8-lead JEDEC SOIC, 8-lead TSSOP, 8-pad UDFN, and 5-lead SOT23
- Die sale options: wafer form and tape and reel available

Enhanced Features in the CS Serial EEPROM Series

- All standard features supported
- 128-bit unique factory-programmed serial number
 - Permanently locked, read-only value
 - Stored in a separate memory area
 - Guaranteed unique across entire CS Series of Serial EEPROMs

1. Description

The Atmel® AT24CS01 and AT24CS02 provides 1024/2048 bits of Serial Electrically Erasable and Programmable Read-only Memory (EEPROM) organized as 128/256 words of eight bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT24CS01/02 is available in space-saving, 8-lead JEDEC SOIC, 8-lead TSSOP, 8-pad UDFN and 5-lead SOT23 packages and is accessed via a 2-wire serial interface. In addition, both devices fully operate from 1.7V to 5.5V V_{CC} .

The AT24CS01/02 provides the additional feature of a factory programmed, guaranteed unique 128-bit serial number, while maintaining all of the traditional features available in the 1-Kbit or 2-Kbit Serial EEPROM. The time consuming step of performing and ensuring true serialization of product on a manufacturing line can be removed from the production flow by employing the CS Series Serial EEPROM. The 128-bit serial number is programmed and permanently locked from future writing during the Atmel production process. Further, this 128-bit location does not consume any of the user read/write area of the 1-Kbit or 2-Kbit Serial EEPROM. The uniqueness of the serial number is guaranteed across the entire CS Series of Serial EEPROMs, regardless of the size of the memory array or the type of interface protocol. This means that as an application's needs for memory size or interface protocol evolve in future generations, any previously deployed serial number from any Atmel CS Series Serial EEPROM part will remain valid.

2. **Pin Descriptions and Pinout**

-	-	8-lead SOIC	8-lead TSSOP
Pin Name	Function		A ₀ [1 8] V
A ₀ - A ₂	Address Inputs	A ₁ 2 7 WP	A ₁ 🗌 2 7 🗋 V
SDA	Serial Data	$A_2 \square 3 \qquad 6 \square SCL$	$A_2 \square 3 \qquad 6 \square S$
SCL	Serial Clock Input	GND 4 5 SDA	$GND \square 4 5 \square S$
WP	Write Protect		
GND	Ground	8-pad UDFN	5-lead SOT23
V _{cc}	Power Supply	V _{CC} 8 1 A ₀ WP 7 2 A ₁	
		SCL 6 3 A2 SDA 5 4 GND	GND 2 SDA 3 4

Figure 2-1. Pin Configuration

Note: For use of 5-lead SOT23, the software A2, A1, and A0 bits in the device address word must be set to zero to properly communicate with the device.

Bottom View

8 Vcc 7 WP 6 🗆 SCL 5 🗌 SDA

□WP

□V_{CC}

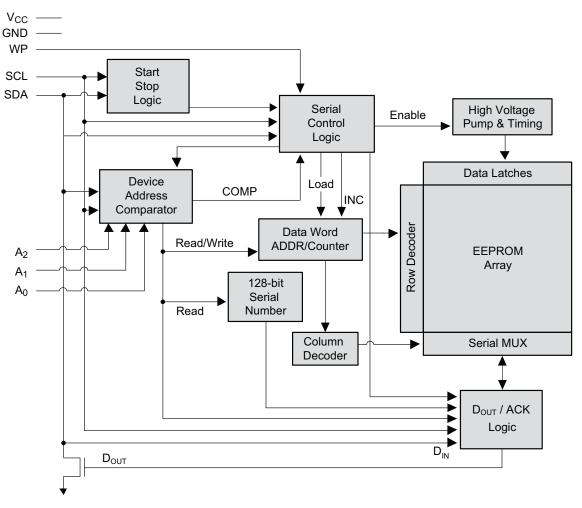
3. Absolute Maximum Ratings

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on any pin with respect to ground–1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current 5.0mA

*Notice: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

4. Block Diagram





5. Pin Description

Serial Clock (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

Serial Data (SDA): The SDA pin is bidirectional for serial data transfer. This pin is open-drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.

Device/Page Addresses (A₂, A₁, A₀): The A₂, A₁ and A₀ pins are device address inputs that are hard wired for the AT24CS01/02. As many as eight 1-Kbit or 2-Kbit devices may be addressed on a single bus system. For more detail, see section, "Device Addressing" on page 10.

Write Protect (WP): AT24CS01/02 has a Write Protect (WP) pin that provides hardware data protection. When the Write Protect pin is connected to ground (GND), normal read/write operations to the full array are possible. When the Write Protect pin is connected to V_{CC} , all write operations to the memory are inhibited but read operations are still possible. This operation is summarized in Table 5-1 below.

Table 5-1. Write Protect

WP Pin	Part of the Array Protected
Status	Atmel AT24CS01/02
At V _{CC}	Full Array
At GND	Normal Read/Write Operations



6. Memory Organization

Atmel AT24CS01, 1K Serial EEPROM: Internally organized with 16 pages of eight bytes each, the 1K requires a 7-bit data word address for random word addressing.

Atmel AT24CS02, 2K Serial EEPROM: Internally organized with 32 pages of eight bytes each, the 2K requires an 8-bit data word address for random word addressing.

Table 6-1. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^{\circ}$ C, f = 1.0MHz, $V_{CC} = 1.7$ V to 5.5V

Symbol	Test Condition	Мах	Units	Conditions
C _{I/O}	Input/Output Capacitance (SDA)	8	pF	V _{I/O} = 0V
C _{IN}	Input Capacitance (A ₀ , A ₁ , A ₂ , SCL)	6	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

Table 6-2. DC Characteristics

Applicable over recommended operating range from: T_{AI} = -40°C to +85°C, V_{CC} = 1.7V to 5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V _{CC}	Supply Voltage		1.7		5.5	V
I _{CC1}	Supply Current V_{CC} = 5.0V	Read at 400kHz		0.4	1.0	mA
I _{CC2}	Supply Current V_{CC} = 5.0V	Write at 400kHz		2.0	3.0	mA
I _{SB1}	Standby Current V _{CC} = 1.7V	$V_{IN} = V_{CC} \text{ or } V_{SS}$			1.0	μA
I _{SB2}	Standby Current V_{CC} = 5.5V	V_{IN} = V_{CC} or V_{SS}			6.0	μA
ILI	Input Leakage Current	V_{IN} = V_{CC} or V_{SS}		0.10	3.0	μA
I _{LO}	Output Leakage Current	V_{OUT} = V_{CC} or V_{SS}		0.05	3.0	μA
V _{IL}	Input Low Level ⁽¹⁾		-0.6		V _{CC} x 0.3	V
V _{IH}	Input High Level ⁽¹⁾		V _{CC} x 0.7		V _{CC} + 0.5	V
V _{OL1}	Output Low Level V _{CC} = $1.7V$	I _{OL} = 0.15mA			0.2	V
V _{OL2}	Output Low Level V_{CC} = 3.0V	I _{OL} = 2.1mA			0.4	V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.

Table 6-3. AC Characteristics

Applicable over recommended operating range from $T_{AI} = -40^{\circ}$ C to +85°C, $V_{CC} = 1.7$ V to 5.5V, CL = 1TTL Gate and 100pF (unless otherwise noted)

		1.	7V	2.5V,	5.0V	
Symbol	Parameter	Min	Max	Min	Max	Units
f _{SCL}	Clock Frequency, SCL		400		1000	kHz
t _{LOW}	Clock Pulse Width Low	1.2		0.4		μs
t _{HIGH}	Clock Pulse Width High	0.6		0.4		μs
t _l	Noise Suppression Time		100		50	ns
t _{AA}	Clock Low to Data Out Valid	0.1	0.9	0.05	0.55	μs
t _{BUF}	Time the bus must be free before a new transmission can start	1.3		0.5		μs
t _{HD.STA}	Start Hold Time	0.6		0.25		μs
t _{SU.STA}	Start Setup Time	0.6		0.25		μs
t _{HD.DAT}	Data In Hold Time	0		0		μs
t _{SU.DAT}	Data In Setup Time	100		100		ns
t _R	Inputs Rise Time ⁽¹⁾		0.3		0.3	μs
t _F	Inputs Fall Time ⁽¹⁾		300		100	ns
t _{su.sto}	Stop Setup Time	0.6		0.25		μs
t _{DH}	Data Out Hold Time	50		50		ns
t _{WR}	Write Cycle Time		5		5	ms
Endurance ⁽¹⁾	3.3V, +25°C, Page Mode		1,000),000		Write Cycles

Note: 1. This parameter is ensured by characterization only.

7. Device Operation

Clock and Data Transitions: The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see Figure 7-4 on page 9). Data changes during SCL high periods will indicate a Start or Stop condition as defined below.

Start Condition: A high-to-low transition of SDA with SCL high is a Start condition which must precede any other command (see Figure 7-5 on page 9).

Stop Condition: A low-to-high transition of SDA with SCL high is a Stop condition. After a read sequence, the Stop command will place the EEPROM in a standby power mode (see Figure 7-5 on page 9).

Acknowledge: All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a zero to acknowledge that it has received each word. This happens during the ninth clock cycle.

Standby Mode: The AT24CS01/02 features a low-power standby mode which is enabled upon power-up as well as after the receipt of the Stop bit and the completion of any internal operations.

2-wire Software Reset: After an interruption in protocol, power loss, or system reset, any 2-wire part can be reset by following these steps:

- 1. Create a start bit condition.
- 2. Clock nine cycles.
- 3. Create another start bit followed by stop bit condition as shown in Figure 7-1.

The device is ready for next communication after above steps have been completed.

Figure 7-1. Software reset

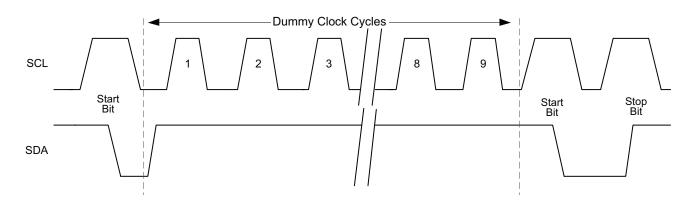
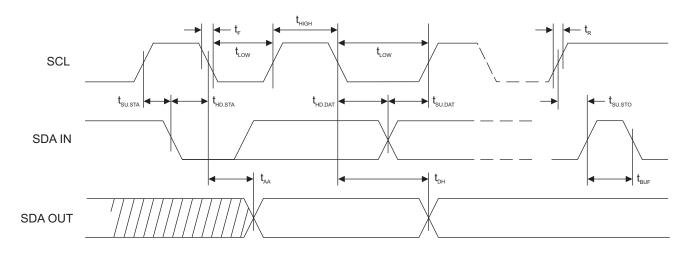


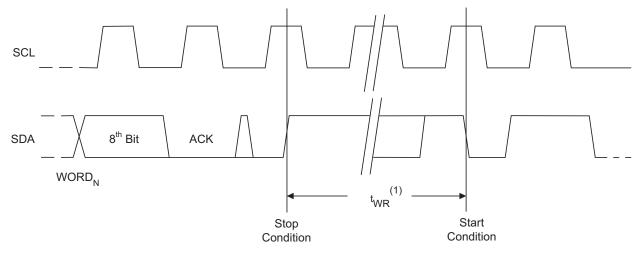
Figure 7-2. Bus Timing



SCL: Serial Clock, SDA: Serial Data I/O

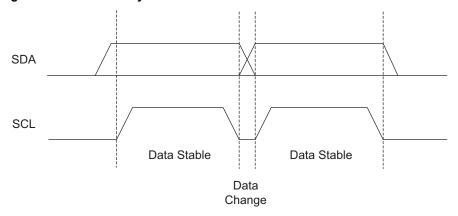
Figure 7-3. Write Cycle Timing

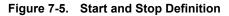
SCL: Serial Clock, SDA: Serial Data I/O



Note: 1. The write cycle time t_{WR} is the time from a valid Stop condition of a write sequence to the end of the internal clear/write cycle.

Figure 7-4. Data Validity





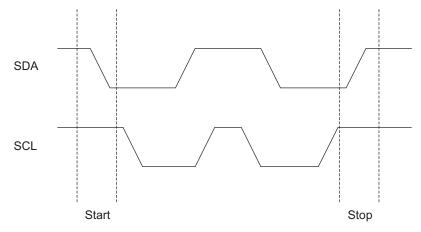
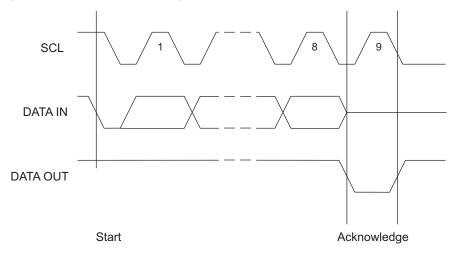


Figure 7-6. Output Acknowledge





8. Device Addressing

Standard EEPROM Access: The 1K and 2K EEPROM device requires an 8-bit device address word following a Start condition to enable the chip for a read or write operation.

The device address word consists of a mandatory `1010' (Ah) sequence for the first four most significant bits as shown in Figure 10-1 on page 12. This is common to all Serial EEPROM devices.

The next three bits are the A2, A1, and A0 device address bits for the 1K and 2K EEPROM. These three bits must compare to their corresponding hard-wired input pins A_2 , A_1 , and A_0 in order for the part to acknowledge.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon a valid compare of the device address with hard-wired input pins A_2 , A_1 , and A_0 , the EEPROM will output a zero. If a compare is not successfully made, the chip will return to a standby state.

Serial Number Access: The AT24CS01 and AT24CS02 utilizes a separate memory block containing a factory programmed 128-bit serial number. Access to this memory location is obtained by beginning the device address word with a `1011' (Bh) sequence.

The behavior of the next three bits (A2, A1, and A0) remain the same as during a standard EEPROM addressing sequence. These three bits must compare to their corresponding hard-wired input pins A_2 , A_1 , and A_0 in order for the part to acknowledge.

The eighth bit of the device address needs be set to a one to read the Serial Number. A zero in this bit position, other than during a dummy write sequence to set the address pointer, will result in a unknown data read from the part. Writing or altering the 128-bit serial number is not possible.

Further specific protocol is needed to read the serial number from of the device. See Read Operations on page 11 for more details on accessing the special feature.

9. Write Operations

Byte Write: A Byte Write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a zero and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a zero and the addressing device, such as a microcontroller, must terminate the write sequence with a Stop condition. At this time the EEPROM enters an internally timed write cycle, t_{WR}, to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the Write is complete (see Figure 10-2 on page 12).

Page Write: The 1K and 2K EEPROM are capable of an 8-byte Page Write. A Page Write is initiated in the same way as a Byte Write, but the microcontroller does not send a Stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to seven data words. The EEPROM will respond with a zero after each data word received. The microcontroller must terminate the Page Write sequence with a Stop condition (see Figure 10-3 on page 12).

The data word address lower three bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the internally generated word address reaches the page boundary, the subsequent byte loaded will be placed at the beginning of the same page. If more than eight data words are transmitted to the EEPROM, the data word address will roll-over and previously loaded data will be overwritten.

Acknowledge Polling: Once the internally timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a Start condition followed by the device address word. The Read/Write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a zero allowing the next read or write sequence to begin.



10. Read Operations

Read operations are initiated in the same way as Write operations with the exception that the Read/Write select bit in the device address word is set to one. There are four read operations:

- Current Address Read
- Random Address Read
- Sequential Read
- Serial Number Read

Current Address Read: The internal data word address counter maintains the last address accessed during the last Read or Write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address roll-over during read is from the last byte of the last memory page to the first byte of the first page. The address roll-over during write is from the last byte of the current page to the first byte of the same page.

Once the device address with the read/write select bit set to one is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an zero but does generate a following Stop condition (see Figure 10-4 on page 12).

Random Read: A Random Read requires a dummy byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another Start condition. The microcontroller now initiates a Current Address Read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a zero but does generate a following Stop condition (see Figure 10-5 on page 13).

Sequential Read: Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will roll-over and the Sequential Read will continue. The Sequential Read operation is terminated when the microcontroller does not respond with a zero but does generate a following Stop condition (see Figure 10-6 on page 13).

Serial Number Read: Reading the serial number is similar to the sequential read sequence but requires use of the device address seen in Figure 10-1 on page 12, a dummy write, and the use of specific word address.

Note: The entire 128-bit value must be read from the starting address of the serial number block to guarantee a unique number.

Since the address pointer of the device is shared between the EEPROM array and the serial number block, a dummy Write Sequence should be performed to ensure the address pointer is set to zero. Random reads of the serial number block are supported but if the previous operation was to the EEPROM array, the address pointer will retain the last access location, incremented by one. Reading the serial number from a location other than the initial address of the block will not result in a unique serial number.

Additionally, the word address must begin with a `10' sequence regardless of the intended address. If a word address other than `10' is used, then the device will output undefined data.

Example: If the application desires to read the first byte of the serial number, the word address input would need to be 80h.

When the end of the 128-bit serial number is reached (16 bytes of data), the data word address will roll-over back to the beginning of the 128-bit serial number. The Serial Number Read operation is terminated when the microcontroller does not respond with an zero (ACK) and instead issues a Stop condition (see Figure 10-7 on page 13).

Density	Access Area	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
1K	EEPROM	1	0	1	0	A ₂	A ₁	A ₀	R/W
	Serial Number	1	0	1	1	A ₂	A ₁	A ₀	1
2K	EEPROM	1	0	1	0	A ₂	A ₁	A ₀	R/W
	Serial Number	1	0	1	1	A ₂	A ₁	A ₀	1
		MOD							1.00

Figure 10-1. Device Address

MSB

LSB

Figure 10-2. Byte Write

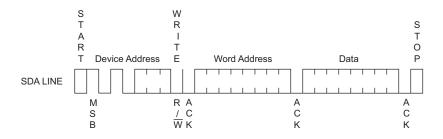


Figure 10-3. Page Write

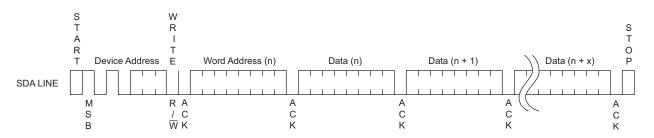
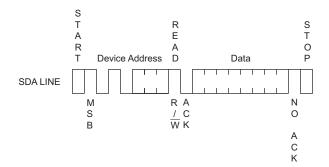
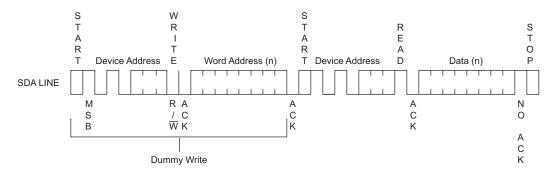


Figure 10-4. Current Address Read









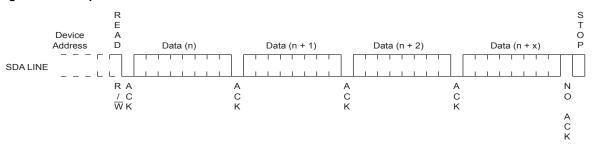
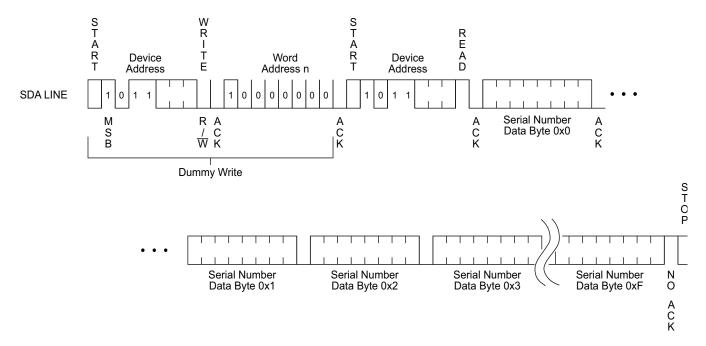


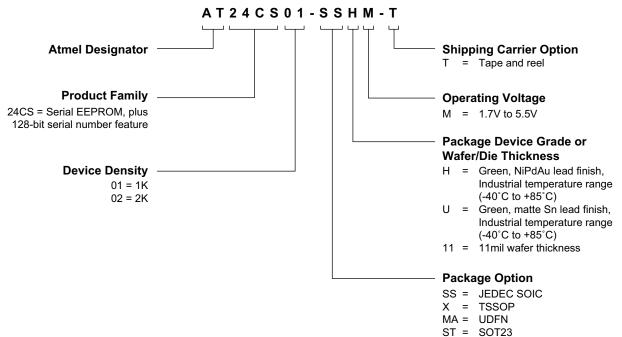
Figure 10-7. Serial Number Read



11. Part Markings

	8-lead SC	OIC		8-lead TSSOP		
			(d	ATHYW ## M AAAAAA	e 🗖 🛛	
	8-lead UD	FN		5-lead SOT-23		
	2.0 x 3.0 mm					
		## HM@ YXX			Top Mark Bottom Mark	
	Note 1 · 🔘 designat	es nin 1				
Catalog Number	Note 1: designat Note 2: Package dra			Code ##: N1		
	Note 2: Package dra		Truncation	Code ##: N1 Code ##: N2		
AT24CS01	Note 2: Package dra		Truncation		Voltages	
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12. Ordering Code Detail



WWU = Wafer unsawn

13. Ordering Information

13.1 Atmel AT24CS01 Ordering Information

Additional package types that are not listed may be available. Please contact Atmel for more details.

Atmel Ordering Code	Package	Voltage	Operation Range
AT24CS01-SSHM-T ⁽¹⁾ (NiPdAu lead finish)	8S1		
AT24CS01-XHM-T ⁽¹⁾ (NiPdAu lead finish)	8X	1.7V to 5.5V	Lead-free/Halogen-free/ Industrial Temperature
AT24CS01-MAHM-T ⁽¹⁾ (NiPdAu lead finish)	8MA2		(–40°C to 85°C)
AT24CS01-STUM-T ⁽¹⁾	5TS1	-	
AT24CS01-WWU11M ⁽²⁾	Wafer Sale	1.7V to 5.5V	Industrial Temperature (–40°C to 85°C)

Notes: 1. T = Tape and reel

- SOIC = 4K units per reel
- TSSOP, UDFN, and SOT23 = 5K units per reel
- 2. For Wafer sales, please contact Atmel Sales.

	Package Type
8S1	8-lead, 0.150" wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8X	8-lead, 4.4mm body, Plastic Thin Shrink Small Outline (TSSOP)
8MA2	8-pad, 2.00mm x 3.00mm body, 0.50mm pitch, Dual No Lead (UDFN)
5TS1	5-lead, 2.90mm x 1.60mm body, Plastic Thin Shrink Small Outline (SOT23)



13.2 Atmel AT24CS02 Ordering Information

Additional package types that are not listed may be available. Please contact Atmel for more details.

Atmel Ordering Code	Package	Voltage	Operation Range
AT24CS02-SSHM-T ⁽¹⁾ (NiPdAu lead finish)	8S1		
AT24CS02-XHM-T ⁽¹⁾ (NiPdAu lead finish)	8X	1.7V to 5.5V	Lead-free/Halogen-free/ Industrial Temperature
AT24CS02-MAHM-T ⁽¹⁾ (NiPdAu lead finish)	8MA2	1.7 V 10 5.5 V	(–40°C to 85°C)
AT24CS02-STUM-T ⁽¹⁾	5TS1		
AT24CS02-WWU11M ⁽²⁾	Wafer Sale	1.7V to 5.5V	Industrial Temperature (–40°C to 85°C)

Notes: 1. T = Tape and reel

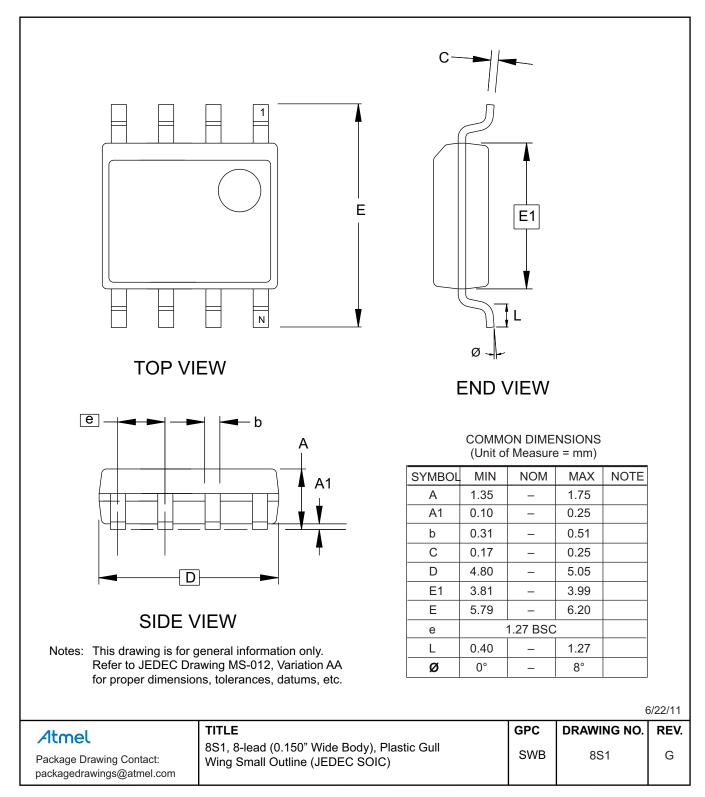
- SOIC = 4K units per reel
- TSSOP, UDFN, and SOT23 = 5K units per reel
- 2. For Wafer sales, please contact Atmel Sales.

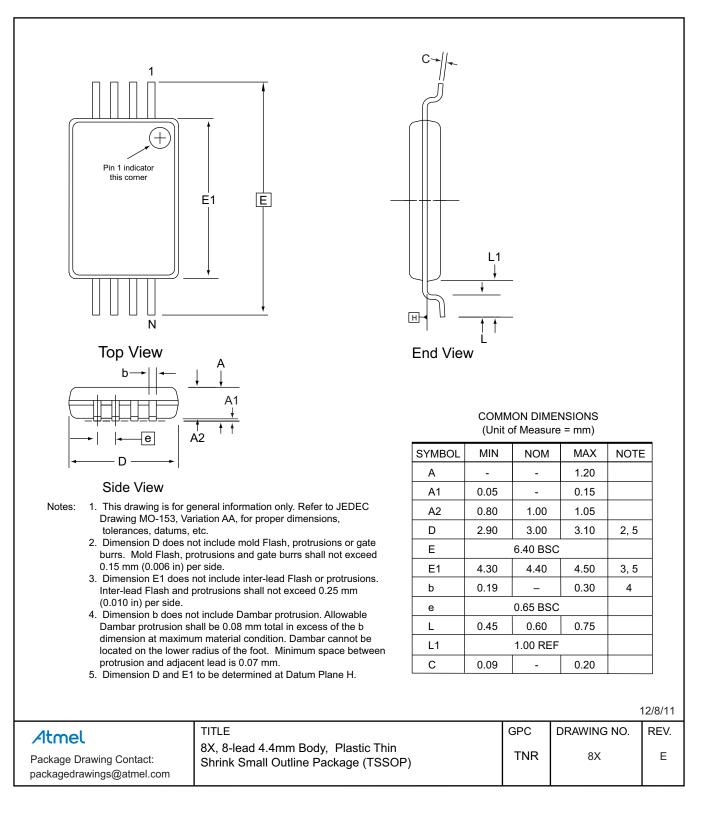
	Package Type
8S1	8-lead, 0.150" wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8X	8-lead, 4.4mm body, Plastic Thin Shrink Small Outline (TSSOP)
8MA2	8-pad, 2.00mm x 3.00mm body, 0.50mm pitch, Dual No Lead (UDFN)
5TS1	5-lead, 2.90mm x 1.60mm body, Plastic Thin Shrink Small Outline (SOT23)

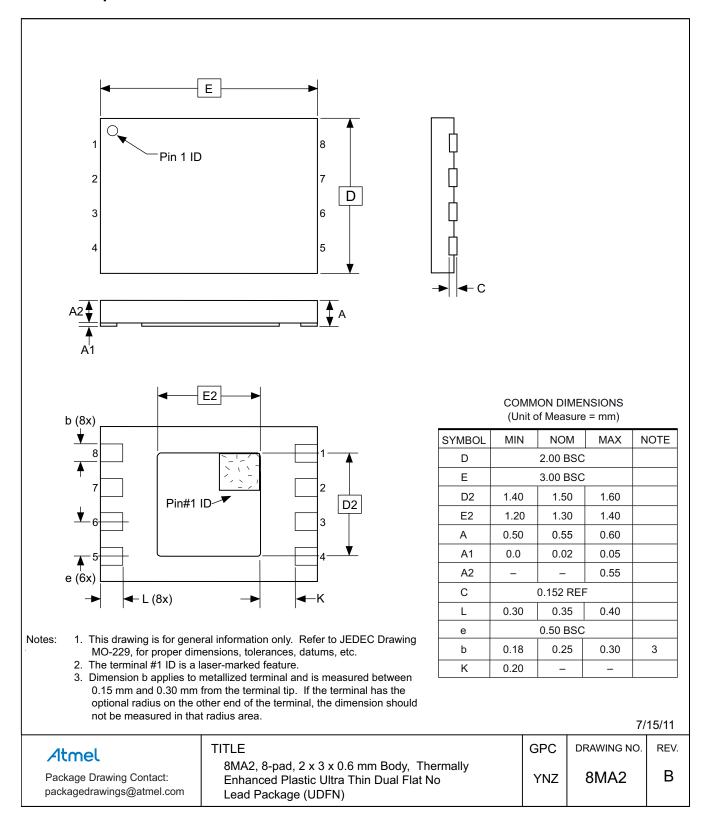


14. Packaging Information

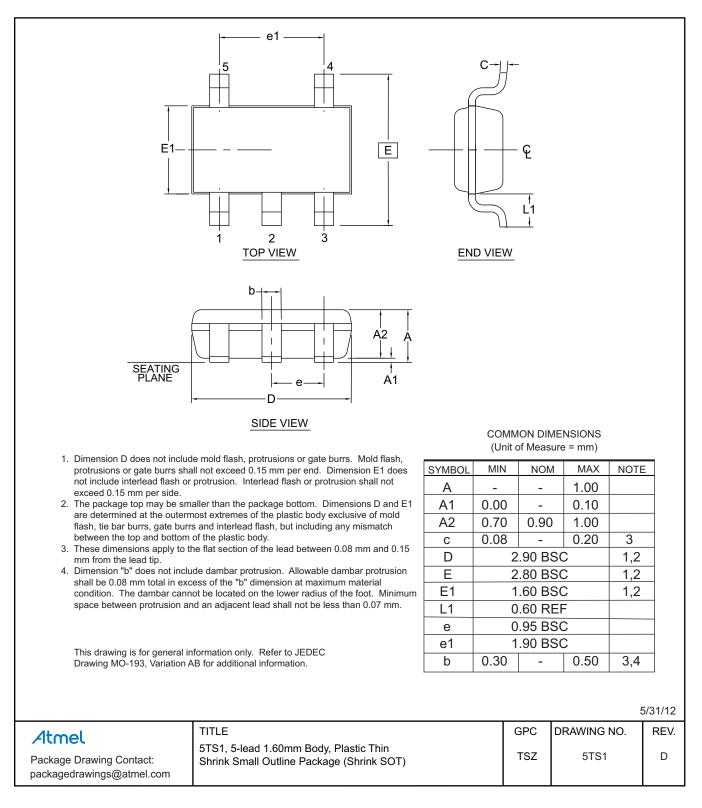
14.1 8S1 — 8-lead JEDEC SOIC







14.4 5TS1 — 5-lead SOT23



15. Revision History

Doc. Rev.	Date	Comments
8815A	06/2012	Initial document release.

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